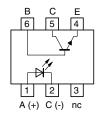
VISHAY.

Vishay Semiconductors

Optocoupler, Phototransistor Output, with Base Connection









18537

DESCRIPTION

The CNY17G consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 6 pin plastic dual inline package.

The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

VDE STANDARDS

These couplers perform safety functions according to the following equipment standards:

• DIN EN 60747-5-5

Optocoupler for electrical safety requirements

• IEC EN 60950/EN 60950

Office machines (applied for reinforced isolation for mains voltage $\leq 400~V_{RMS})$

VDE 0804

Telecommunication apparatus and data processing

• IEC 60065

Safety for mains-operated electronic and related household apparatus

AGENCY APPROVALS

- UL1577, file no. E76222 system code A, double protection
- BSI: BS EN 41003, BS EN 60065 (BS 415), BS EN 60950 (BS 7002), certificate number 7081 and 7402
- DIN EN 60747-5-5
- FIMKO (SETI): EN 60950, certificate no. 12399

FEATURES

- Isolation test voltage 5300 V_{RMS}
- Isolation materials according to UL94-VO





Climatic classification 55/100/21 (IEC 60068 part 1)

RoHS COMPLIANT

- Special construction: therefore, extra low coupling capacity of typical 0.3 pF, high common mode rejection
- · Low temperature coefficient of CTR
- Rated impulse voltage (transient overvoltage)
 V_{IOTM} = 6 kV peak
- Isolation test voltage (partial discharge test voltage) $V_{pd} = 1.6 \; kV$
- Rated isolation voltage (RMS includes DC)
 V_{IOWM} = 600 V_{RMS} (848 V peak)
- Rated recurring peak voltage (repetitive) $V_{IORM} = 600 V_{RMS}$
- Thickness through insulation ≥ 0.75 mm
- Creepage current resistance according to VDE 0303/ IEC 60112 comparative tracking index: CTI = 275
- · CTR offered in 4 groups
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

- Switch-mode power supplies
- · Line receiver
- · Computer peripheral interface
- Microprocessor system interface
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
 - for appl. class I IV at mains voltage ≤ 300 V
- for appl. class I III at mains voltage \leq 600 V according to DIN EN 60747-5-5

ORDER INFORMATION				
PART	REMARKS			
CNY17G-1	CTR 40 to 80 %, DIP-6			
CNY17G-2	CTR 63 to 125 %, DIP-6			
CNY17G-3	CTR 100 to 200 %, DIP-6			
CNY17G-4	CTR 160 to 320 %, DIP-6			

Note

G = leadform 10.16 mm; G is marked on the body.

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ABSOLUTE MAXIMUM RAT	INGS ⁽¹⁾			
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT	·			
Reverse voltage		V_{R}	5	V
Forward current		I _F	60	mA
Forward surge current	t _p ≤ 10 μs	I _{FSM}	3	Α
Power dissipation		P _{diss}	100	mW
Junction temperature		Tj	125	°C
OUTPUT	·			
Collector emitter voltage		V _{CEO}	32	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		Ic	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA
Power dissipation		P _{diss}	150	mW
Junction temperature		Tj	125	°C
COUPLER				
Isolation test voltage (RMS)		V _{ISO}	3750	V_{RMS}
Total power dissipation		P _{tot}	250	mW
Ambient temperature range		T _{amb}	- 55 to + 100	°C
Storage temperature range		T _{stg}	- 55 to + 125	°C
Soldering temperature (2)	2 mm from case, t ≤ 10 s	T _{sld}	260	°C

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽²⁾ Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTCS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I _F = 50 mA	V _F		1.25	1.6	V		
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j		50		pF		
OUTPUT								
Collector emitter voltage	I _C = 1 mA	V _{CEO}	32			V		
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V		
Collector emitter cut-off current	$V_{CE} = 10 \text{ V}, I_F = 0$	I _{CEO}		10	100	nA		
COUPLER								
AC isolation test voltage (RMS)	f = 50 Hz, t = 1 s	V _{ISO}	3750			V_{RMS}		
Collector emitter saturation voltage	I _F = 10 mA, I _C = 1 mA	V _{CEsat}			0.3	V		
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c		110		kHz		
Coupling capacitance	f = 1 MHz	C _k		0.3		pF		

Note

 T_{amb} = 25 °C, unless otherwise specified.

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

⁽¹⁾ $T_{amb} = 25$ °C, unless otherwise specified.



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CURRENT TRANSFER RATIO								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		CNY17G-1	CTR	40		80	%	
	V - 5 V I - 10 mA	CNY17G-2	CTR	63		125	%	
l _C /l _F	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	CNY17G-3	CTR	100		200	%	
		CNY17G-4	CTR	160		320	%	
		CNY17G-1	CTR	13			%	
	V - 5 V - 1 m A	CNY17G-2	CTR	22			%	
	$V_{CE} = 5 \text{ V}, I_F = 1 \text{ mA}$	CNY17G-3	CTR	34			%	
		CNY17G-2	CTR	56		200	%	

MAXIMUM SAFETY RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward current		I _F			130	mA	
OUTPUT							
Power dissipation		P _{diss}			265	mW	
COUPLER							
Rated impulse voltage		V _{IOTM}			6	kV	
Safety temperature		T _{si}			150	°C	

Note

According to DIN EN 60747-5-5 (see figure 1). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V_{pd}	1.6			kV	
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 2)	V_{IOTM}	6			kV	
		V_{pd}	1.3			kV	
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω	
	$V_{IO} = 500 \text{ V}, T_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	10 ¹¹			Ω	
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω	

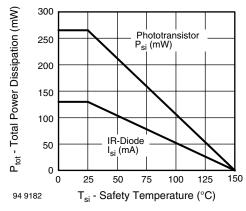


Fig. 1 - Derating Diagram

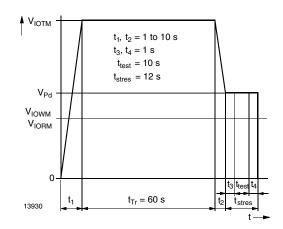


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5/DIN EN 60747-; IEC60747

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SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω , (see figure 3)	t _d		4.0		μs	
Rise time	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω , (see figure 3)	t _r		7.0		μs	
Fall time	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω , (see figure 3)	t _f		6.7		μs	
Storage time	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω , (see figure 3)	t _s		0.3		μs	
Turn-on time	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω , (see figure 3)	t _{on}		11.0		μs	
Turn-off time	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω , (see figure 3)	t _{off}		7.0		μs	
Turn-on time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω , (see figure 4)	t _{on}		25		μs	
Turn-off time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω , (see figure 4)	t _{off}		42.5		μs	

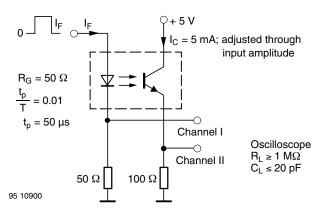


Fig. 3 - Test Circuit, Non-Saturated Operation

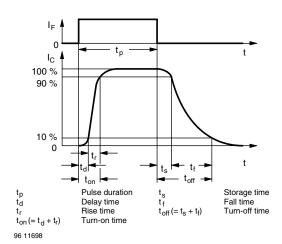


Fig. 5 - Switching Times

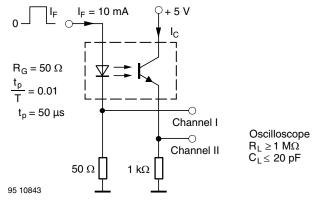


Fig. 4 - Test Circuit, Saturated Operation



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TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

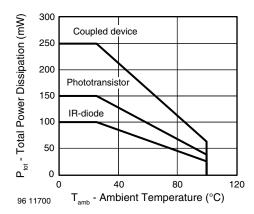


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

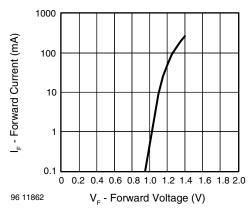


Fig. 7 - Forward Current vs. Forward Voltage

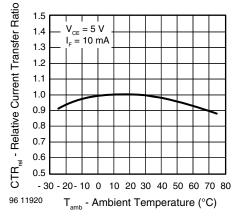


Fig. 8 - Relative Current Transfer Ratio vs. Ambient Temperature

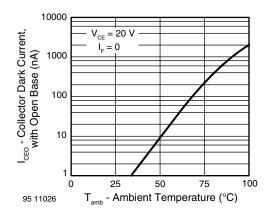


Fig. 9 - Collector Dark Current vs. Ambient Temperature

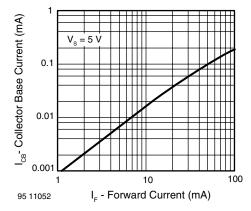


Fig. 10 - Collector Base Current vs. Forward Current

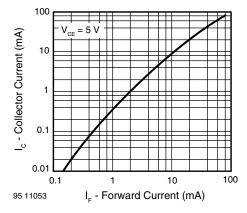


Fig. 11 - Collector Current vs. Forward Current

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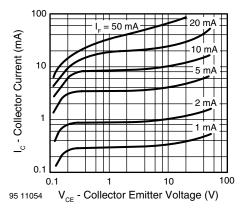


Fig. 12 - Collector Current vs. Collector Emitter Voltage

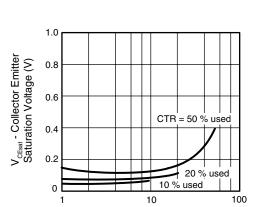


Fig. 13 - Collector Emitter Saturation Voltage vs. Collector Current

I_c - Collector Current (mA)

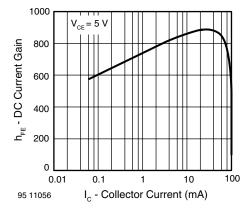


Fig. 14 - DC Current Gain vs. Collector Current

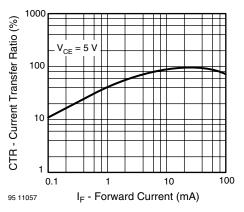


Fig. 15 - Current Transfer Ratio vs. Forward Current

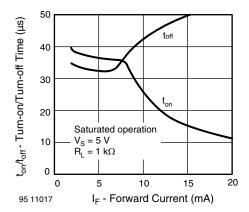


Fig. 16 - Turn-on/off Time vs. Forward Current

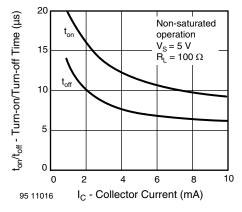


Fig. 17 - Turn-on/off Time vs. Collector Current

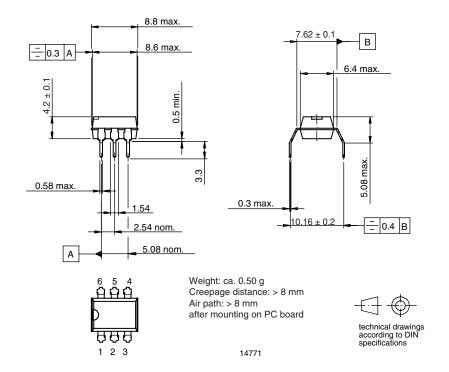
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Optocoupler, Phototransistor Output, with Base Connection

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PACKAGE DIMENSIONS in millimeters



CNY17G

Vishay Semiconductors

Optocoupler, Phototransistor Output, with Base Connection



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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